

Description

The 74HCT00 provides provides four independent 2-input NAND gates with standard push-pull outputs. The device is designed for operation with a power supply range of 4.5V to 5.5V.

The gates perform the Boolean function:

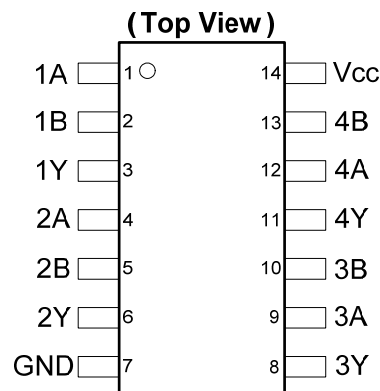
$$Y = \overline{A \bullet B} \text{ or } Y = \overline{A} + \overline{B}$$

Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Pin Compatible with Low Power Schottky (LSTTL)
- Inputs Are TTL Voltage Level Compatible
- Sinks or sources 4mA at Vcc = 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Range of Package Options SO-14 and TSSOP-14
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments



SO-14 / TSSOP-14

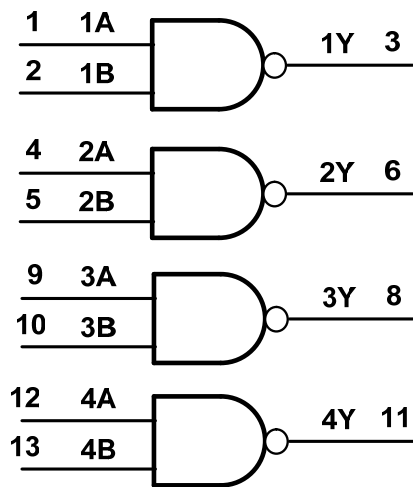
Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box

Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	V _{CC}	Supply Voltage

Logic Diagram



Function Table

Inputs		Output
A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

Absolute Maximum Ratings (Note 4) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to +7.0	V
V_I	Input Voltage Range (Note 5)	-0.5 to +7.0	V
I_{IK}	Input Clamp Current $V_I < -0.5\text{V}$ or $V_I > V_{CC} + 0.5\text{V}$	± 20	mA
I_{OK}	Output Clamp Current $V_O < -0.5\text{V}$ or $V_O > V_{CC} + 0.5\text{V}$	± 20	mA
I_O	Continuous Output Current $-0.5\text{V} < V_O < V_{CC} + 0.5\text{V}$	+/- 25	mA
I_{CC}	Continuous Current Through V_{CC}	50	mA
I_{GND}	Continuous Current Through GND	-50	mA
T_J	Operating Junction Temperature	-40 to +150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-65 to +150	$^\circ\text{C}$
P_{TOT}	Total Power Dissipation	500	mW

- Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
5. Input Voltage cannot exceed V_{CC} to the extent the Maximum clamp current is exceeded.

Recommended Operating Conditions (Note 6) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply Voltage		4.5	5.5	V
V_I	Input Voltage		0	V_{CC}	V
V_O	Output Voltage		0	V_{CC}	V
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate	$V_{CC} = 4.5\text{V}$ to 5.5V		500	ns/V
T_A	Operating Free-Air Temperature		-40	+125	$^\circ\text{C}$

Note: 6. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V_{CC}	$T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$		$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		Unit
				Min	Max	Min	Max	
V_{IH}	High-level Input Voltage		4.5V to 5.5V	2.0		2.0		V
V_{IL}	Low-level Input Voltage		4.5V to 5.5V		0.8		0.8	V
V_{OH}	High-level Output Voltage	$I_{OH} = -20\mu\text{A}$	4.5V	4.4		4.4		V
		$I_{OH} = -4\text{mA}$	4.5V	3.84		3.70		
V_{OL}	Low-level Output Voltage	$I_{OL} = 20\mu\text{A}$	4.5V		0.1		0.1	V
		$I_{OL} = 4.0\text{mA}$	4.5V		0.33		0.4	
I_I	Input Current	$V_I = \text{GND}$ to 6.0V	6.0V		± 1		± 1	μA
I_{CC}	Supply Current	$V_I = \text{GND}$ or V_{CC} , $I_O = 0$	6.0V		20		40	μA
ΔI_{CC}	Additional Supply Current	One Input at $V_{CC} - 2.1\text{V}$ Other pins at V_{CC} or GND	4.5V to 5.5V		675		735	μA

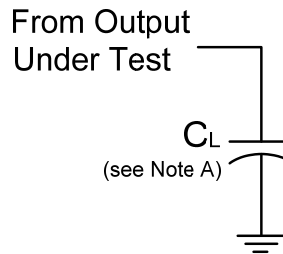
Switching Characteristics

Symbol	Parameter	Test Conditions	V _{CC}	T _A = +25°C			-40°C to +85°C	-40°C to +125°C	Unit
				Min	Typ	Max	Max	Max	
t _{PD}	Propagation Delay A _N to Y _N	Figure 1 C _L = 50pF	4.5V	—	12	22	24	29	ns
t _t	Transition Time	Figure 1 C _L = 50pF	4.5V	—	7	22	22	29	ns

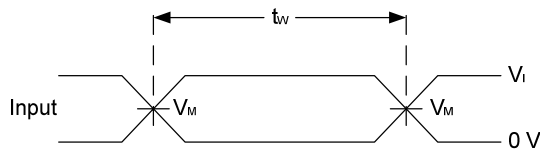
Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

Parameter		Test Conditions	V _{CC} = 5.5V	Unit
			Typ	
C _{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	12	pF
C _i	Input Capacitance	V _i = V _{CC} – or GND	3.5	pF

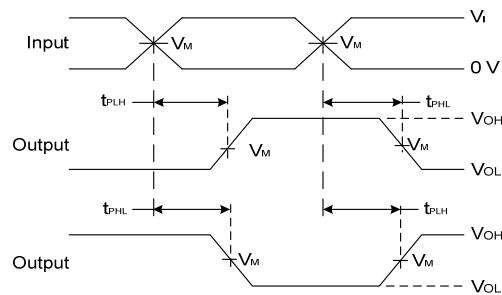
Parameter Measurement Information



V _{CC}	Inputs		V _M	C _L
	V _i	t _r /t _f		
4.5V	3.0V	3ns	1.5V	V _{OH} /2



**Voltage Waveform
Pulse Duration**

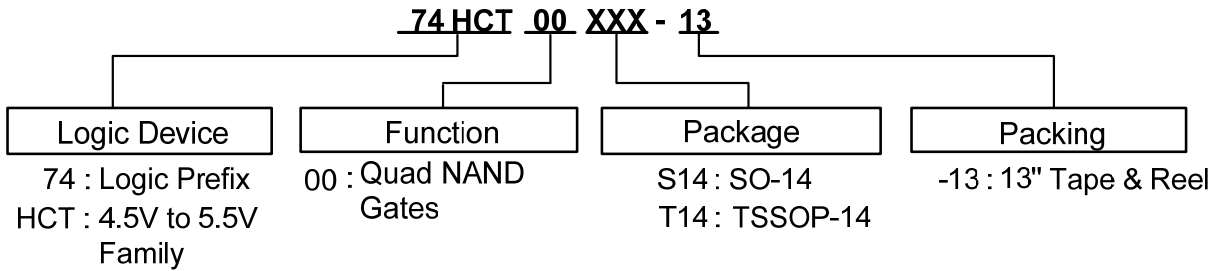


**Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs**

- Notes:
- A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLH} and t_{PHL} are the same as t_{PD}.

Figure 1 Load Circuit and Voltage Waveforms

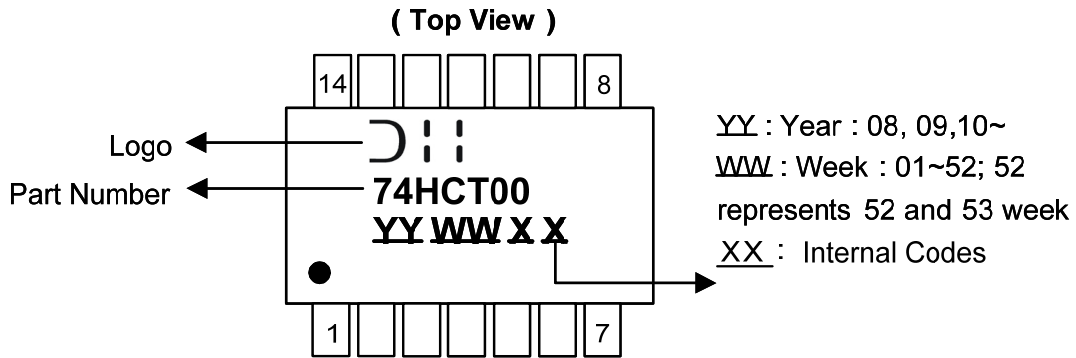
Ordering Information



Device	Package Code	Packaging	7" Tape and Reel	
			Quantity	Part Number Suffix
74HCT00S14-13	S14	SO-14	2500/Tape & Reel	-13
74HCT00T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Marking Information

(1) SO-14, TSSOP-14

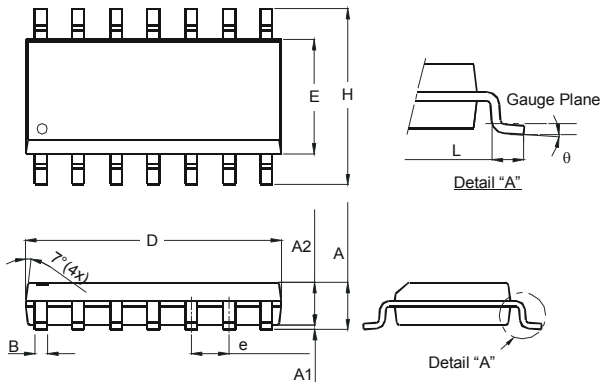


Part Number	Package
74HCT00S14	SO-14
74HCT00T14	TSSOP-14

Package Outline Dimensions (All dimensions in mm.)

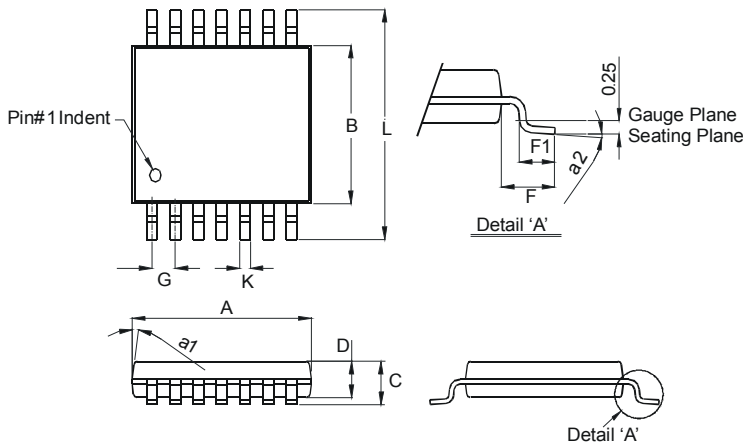
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

Package Type: SO-14



SO-14		
Dim	Min	Max
A	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
B	0.33	0.51
D	8.53	8.74
E	3.80	3.99
e	1.27 Typ	
H	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

Package Type: TSSOP-14

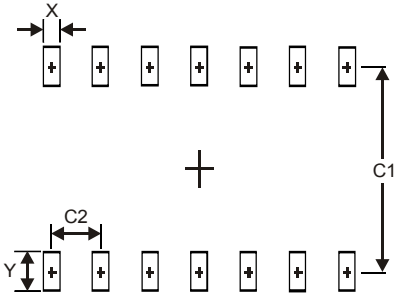


TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
A	4.9	5.10
B	4.30	4.50
C	—	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		

Suggested Pad Layout

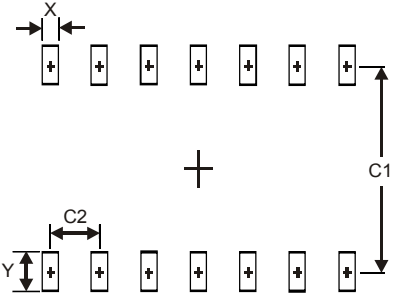
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for latest version.

Package Type: SO-14



Dimensions	Value (in mm)
X	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65

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